DSC9F01

Silicon NPN epitaxial planar type

For high-frequency amplification DSC5F01 in SSMini3 type package

Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- \bullet High transition frequency $f_{\rm T}$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	15	V
Collector-emitter voltage (Base open)	V _{CEO}	10	V
Emitter-base voltage (Collector open)	V _{EBO}	3	V
Collector current	I _C	50	mA
Collector power dissipation	P _C	125	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Package

- Code
- SSMini3-F3-B
- Pin Name
 - 1. Base
 - 2. Emitter
 - 3. Collector

Marking Symbol: C7

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$	10			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	3			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 10 \text{ V}, I_E = 0$			1	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 4 V, I_C = 5 mA$	75		220	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 20 \text{ mA}, I_{\rm B} = 4 \text{ mA}$			0.5	V
Transition frequency	f _T	$V_{CE} = 4 V, I_C = 5 mA$		1.9		GHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 4 \text{ V}, I_E = 0 \text{ , } f = 1 \text{ MHz}$		1.2		pF
Collector-base parameter	$r_{bb}' \bullet C_C$	$V_{CE} = 4 V, I_C = 5 mA, f = 31.9 MHz$		12		ps
Reverse transfer capacitance (Common base)	C _{rb}	$V_{CE} = 4 V, I_C = 0, f = 1 MHz$		0.6		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

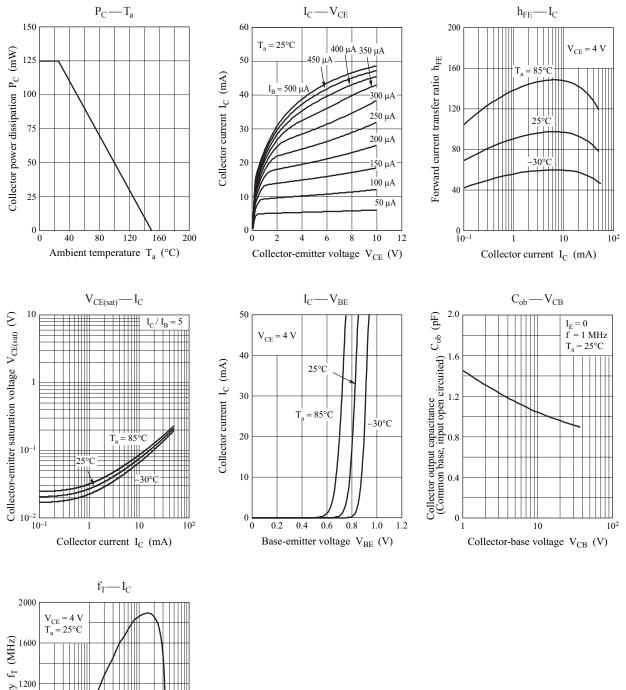
2. *: Rank classification

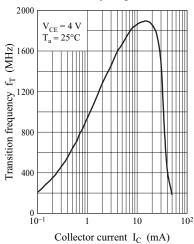
Code	Р	Q	0	
Rank	Р	Q	No-rank	
$h_{\rm FE}$	75 to 130	110 to 220	75 to 220	
Marking Symbol	C7P	C7Q	C7	

Product of no-rank is not classified and have no marking symbol for rank.

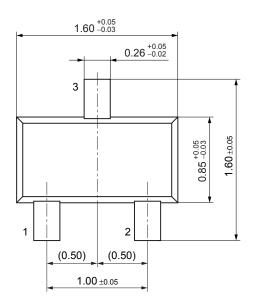
DSC9F01

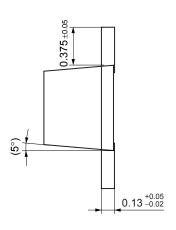
Panasonic

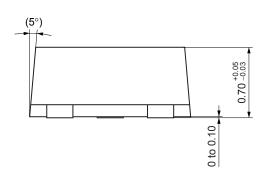


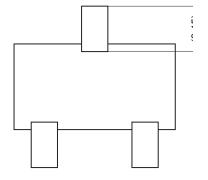


Unit: mm









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